

RJK0702DPN-E0

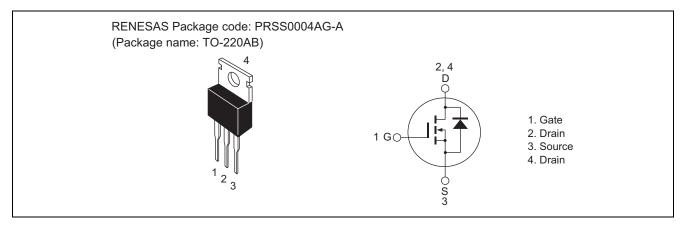
N-Channel MOS FET 75 V, 90 A, 4.8 m Ω

R07DS0623EJ0200 Rev.2.00 Aug 24, 2012

Features

- High speed switching
- Low drive current
- Low on-resistance $R_{DS(on)} = 3.9 \text{ m}\Omega \text{ typ.}$ (at $V_{GS} = 10 \text{ V}$)
- Package TO-220AB

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$	
Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	75	V	
Gate to source voltage	V _{GSS}	±20	V	
Drain current	I _D	90	А	
Drain peak current	I _{D (pulse)} Note1	270	А	
Body-drain diode reverse drain current	I _{DR}	90	А	
Avalanche current	I _{AP} ^{Note2}	45	А	
Avalanche energy	E _{AS} Note2	304	mJ	
Channel dissipation	Pch Note3	150	W	
Channel to case thermal impedance	θch-c	0.83	°C/W	
Channel temperature	Tch	150	٥C	
Storage temperature	Tstg	-55 to +150	٥C	

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at L = 100 μH , Tch = 25°C, Rg $\geq 50 \Omega,$

3. Tc = 25°C



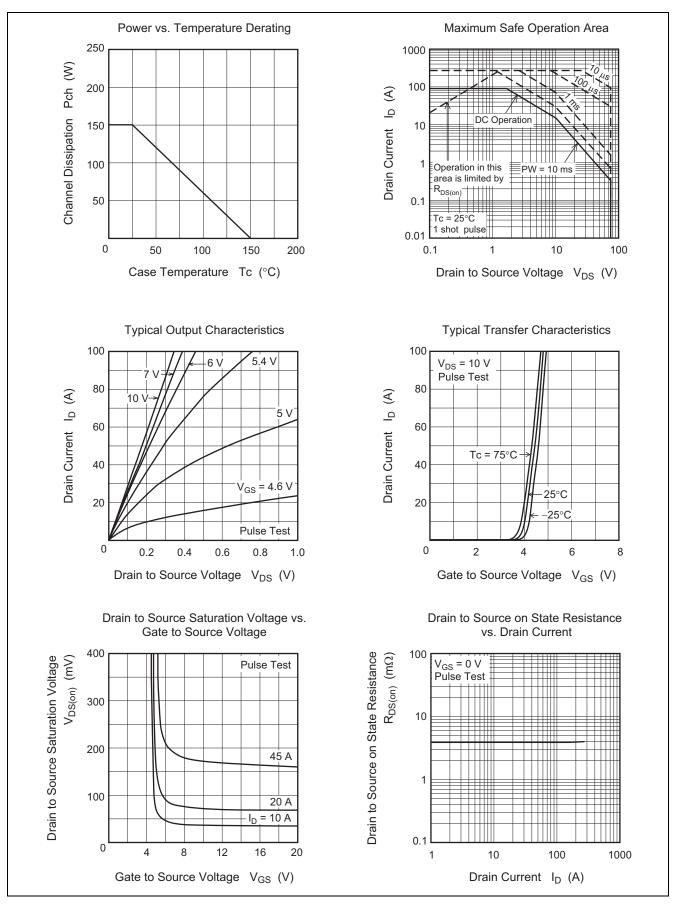
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	75	—	_	V	$I_D = 10mA, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	—	±0.1	μA	$V_{GS}=\pm 20~V,~V_{DS}=0$
Zero gate voltage drain current	I _{DSS}	_	—	1	μA	$V_{DS} = 75 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	2.0	—	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	3.9	4.8	mΩ	$I_D = 45 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance						Noted
Forward transfer admittance	y _{fs}	—	110	—	S	$I_D = 45 \text{ A}, V_D = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	6450		pF	V _{DS} = 10 V
Output capacitance	Coss	—	1240	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	310	_	pF	
Gate Resistance	Rg	_	1.5	—	Ω	
Total gate charge	Qg	_	89	—	nC	V _{DD} = 25 V
Gate to source charge	Qgs	_	33	—	nC	V _{GS} = 10 V, I _D = 45 A
Gate to drain charge	Qgd	_	13	—	nC	
Turn-on delay time	t _{d(on)}	_	40	—	ns	$\label{eq:GS} \begin{array}{l} V_{GS} = 10 \ V \\ I_D = 45 \ A \\ V_{DD} \cong 30 \ V \\ Rg = 4.7 \ \Omega \end{array}$
Rise time	tr	_	12	—	ns	
Turn-off delay time	t _{d(off)}	_	70	_	ns	
Fall time	t _f	_	15	—	ns	
Body-drain diode forward voltage	V _{DF}	—	0.85	1.5	V	$I_F = 90 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery time	t _{rr}	_	60	_	ns	$I_F = 90 \text{ A}, V_{GS} = 0$
						di _F /dt = 100 A/µs

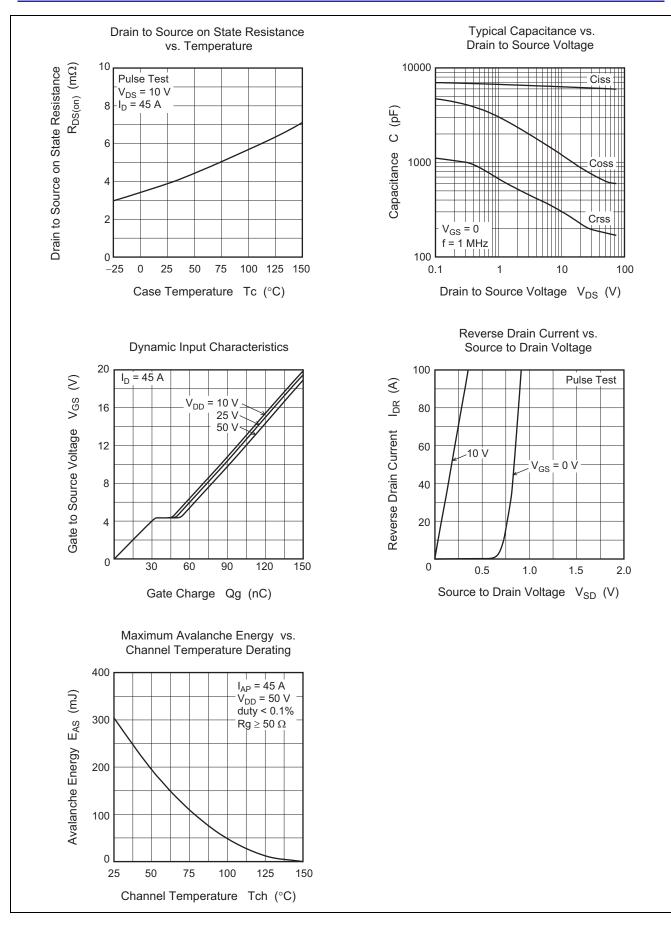
Notes: 4. Pulse test



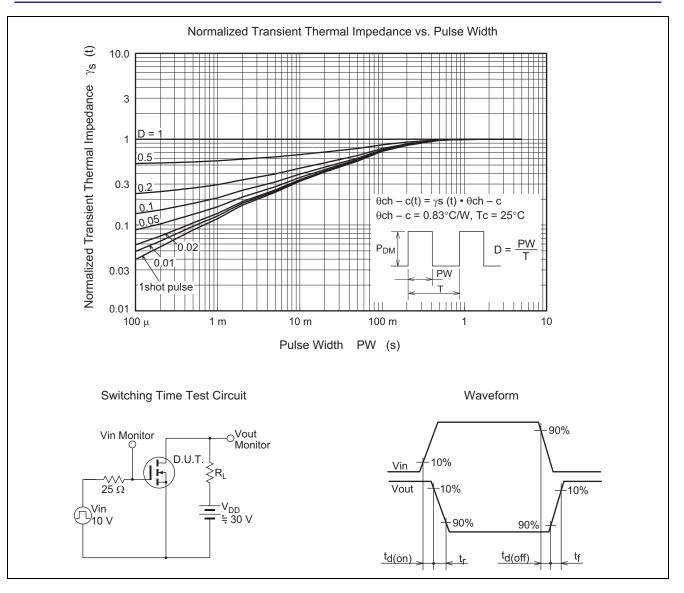
Main Characteristics





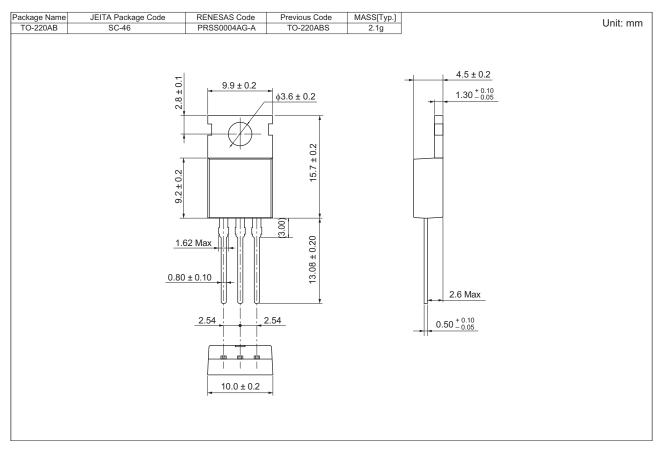








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK0702DPN-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".



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